

مخبر التجنيد في الأجهزة الجوالة، المتواصلة والمتعاونة Innovation of COMmunicant and COoperative Mobiles

Autumn School of EMC: IoT&IoT

2nd to 4th November 2023

Interferences of Things & IoT

Fethi CHOUBANI





مخبر التجديد في الاجهزة الجوالة، المتواصلة والمتعاونة Innovation of COMmunicant and COoperative Mobiles

Outline

Introduction
Definitions
Coupling mechanisms
Measurements
Mitigation techniques

To be continued....



Introduction



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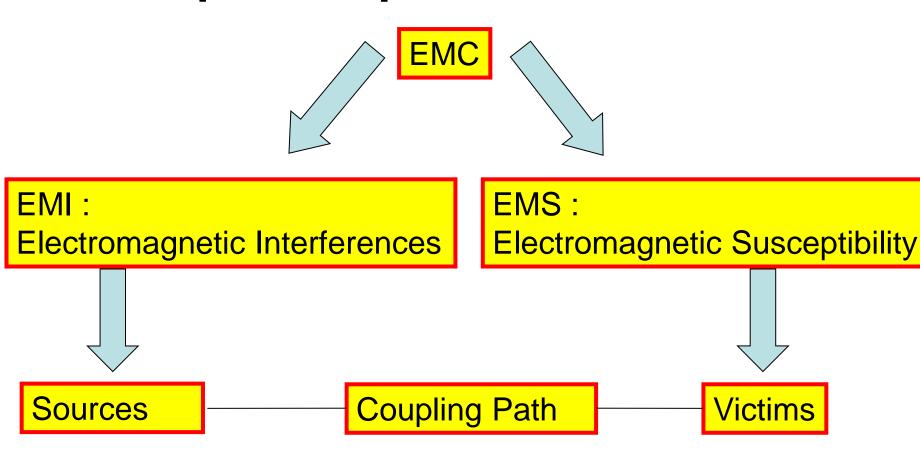
- Certification from iNARTE (International Association for Radio, Telecommunications and Electromagnetics)
- Pre-Certification preparation for students, PhD students, Engineers,
 with collaboration of ISIKef (2h Exam scheduled at the end)
- EMI/EMS issues reenforced by IoT components and devices
 (See opening talk)
- EMC is a multidisciplinary field, and no one knows everything:
 Support by many friends and colleagues (Amplifiers, Budget link, Electrical networks, Filters, Signals and Spectra, TRLs Antennas and Propagation) + Student Posters (complementary content)
- 2 Credits for PhD students: Support by EDTIC
- Present High topics: Panel Discussions (Potential health risks of EM fields and 5G controversy)







The ability of a device, unit of equipment, or system to function satisfactorily in its electromagnetic environment without introducing intolerable electromagnetic disturbances to anything in that environment. [IEC 61000-1-1]



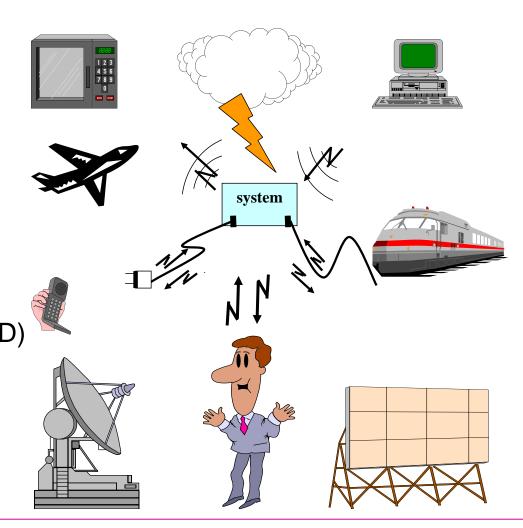


Sources of EMI

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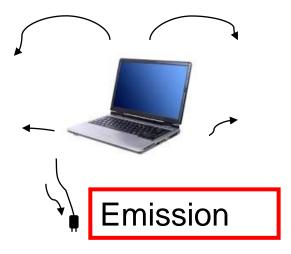
RF devices Electronics/computers Cell phones/radios Wireless/RF energy Microwave equipment Power lines Electric motors Electrostatic discharge (ESD) Lightning (LEMP) Nuclear event (HEMP) Others.....





Conduction/Radiation





Conduction and/or Radiation



EMI is defined as any unwanted electrical or electromagnetic energy that causes undesirable responses, degraded performance, or failure in electronic equipment.

Four (4) coupling mechanisms:

- Common impedance (or conducted) coupling
- Electric field (or capacitive) coupling
- Magnetic field (or inductive) coupling
- Radiated coupling

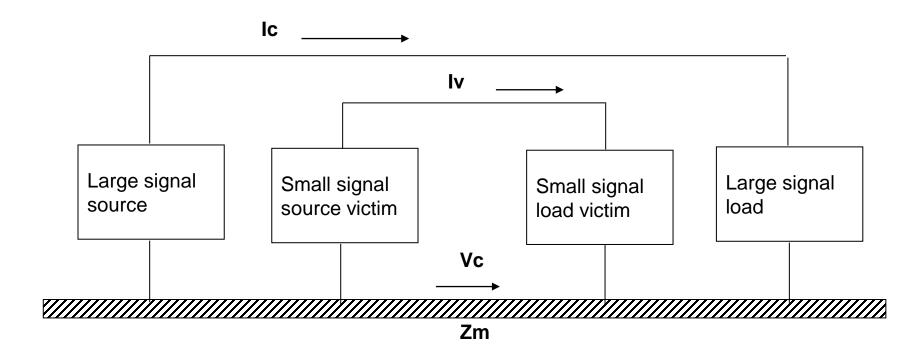


Coupling Mechanisms



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Common impedance coupling



Zm: finite common impedance between large and small signal circuits

$$Vc = Zm (Ic + Iv)$$

Solution for reduction of Vc: single point or star grounding arrangement



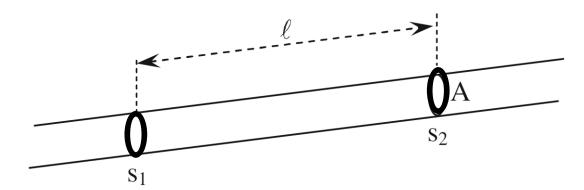
Common impedance coupling

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$$\delta = \frac{1}{\sqrt{\pi F \mu \sigma}}$$

F: Frequency (Hz)

μ : Permeability



 ρ : resistivity (Ω .m)

 $\sigma: 1/\rho: Conductivity(S/m)$

Silver: $\rho = 16.10^{-9}$

Au: $\rho = 22.10^{-9}$

Tin: $\rho = 111.10^{-9}$

Copper: $\rho = 17.10^{-9}$

Aluminium: $\rho = 28.10^{-9}$

•••••

l: length (m)

A: Area (m²)

Others:

Water: $\rho = 1.8 \ 10^5$ Glass: $\rho = 10^{17}$

Polystyrene: $\rho = 10^{20}$



Common impedance coupling

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Resistance of a rod wire at low frequencies (i.e. $\delta >> a$):

$$R = \frac{l}{\sigma A} = \frac{l}{\sigma \pi a^2}$$

Resistance of a rod wire at high frequencies (i.e. $\delta \ll a$):

$$R = \frac{l}{\sigma A} = \frac{l}{\sigma 2\pi a \delta}$$

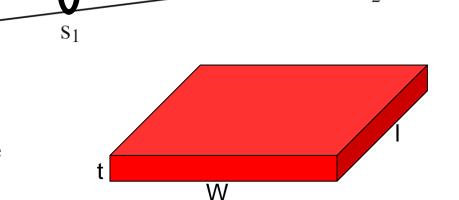
Resistance of a circuit board trace at low frequencies (i.e. $\delta >> t$):

$$R = \frac{l}{\sigma A} = \frac{l}{\sigma wt}$$

Resistance of a circuit board trace at high frequencies (i.e. $\delta \ll t$):

$$R = \frac{l}{\sigma A} = \frac{l}{\sigma 2wt}$$

(we assume t<<w)



a= radius of wire

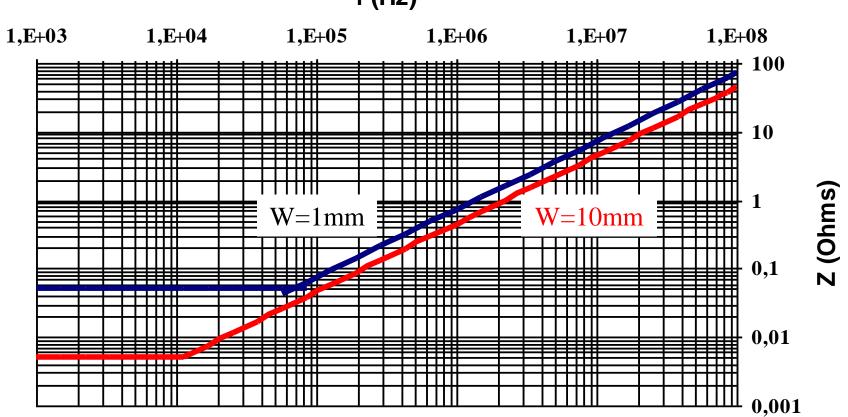


Common impedance coupling

nnovation of COMmunicant and COoperative Mobiles

Impédance de pistes de Cu de 10 cm (e=35um)







Exercise



and an arrangement and a second representative Mobiles.

The DC resistance per unit length of a cylindrical copper wire with a 0.5mm Diameter is approximately:

- a) $80 \text{ m}\Omega/\text{m}$
- b) $800 \text{ m}\Omega/\text{m}$
- c) $1.80 \Omega/m$
- d) $180 \Omega/m$

Answer:

The conductivity of copper is approximately 6x10⁷ S/m. The resistance per unit length of wire is therefore:

$$R = \frac{l}{\sigma A} = \frac{l}{\sigma \pi a^2}$$

$$R = \frac{1}{(6x10^7 S/m)\pi(0.25x10^{-3}m)^2} \approx 85 m\Omega$$

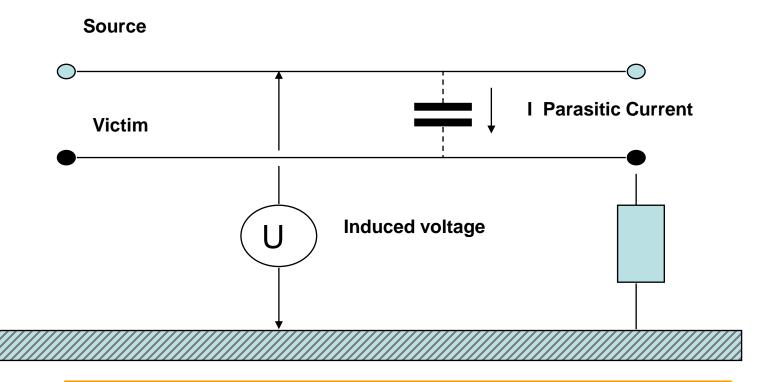


Coupling Mechanisms

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xTalk: Capacitive coupling



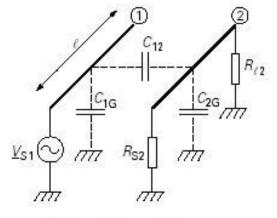
$$V1 \Rightarrow E \equiv \text{mutual capacitance}$$



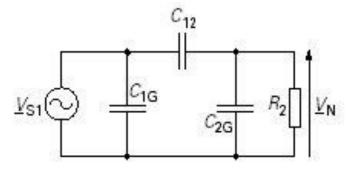
Coupling Mechanisms

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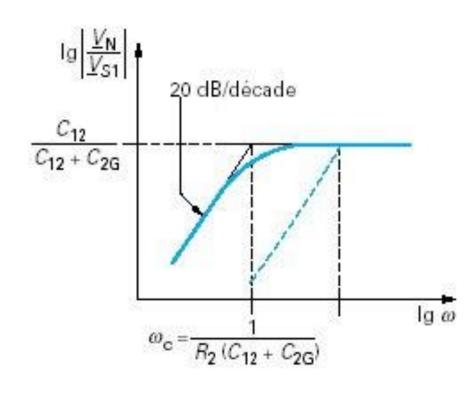
xTalk: Capacitive coupling



(a) description physique



(b) schéma équivalent

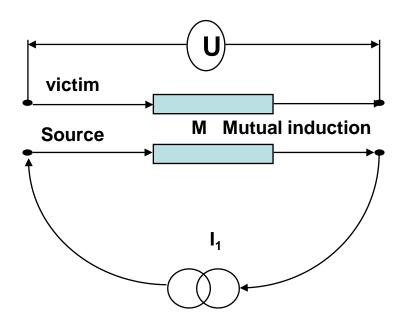


© variation du module de la fonction de transfert



xTalk: Inductive Coupling

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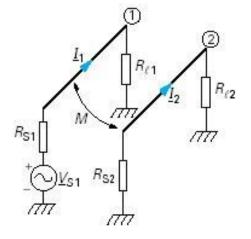


Lentz: $I \Rightarrow B \Rightarrow \phi \Rightarrow \text{induced voltage}$

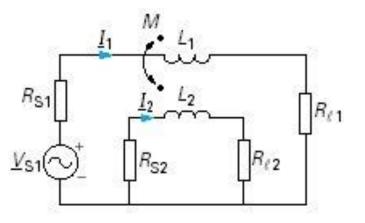


xTalk: Inductive Coupling

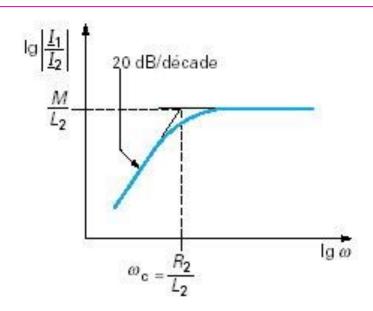
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(a) description physique



(b) modèle équivalent



(c) variation du module de la fonction de transfert

$$rac{I_2}{I_1}$$
 = $-rac{jM\omega}{R_2} \over 1+jrac{L_2\omega}{R}$ Where: $R_2=R_{ch2}+R_{G2}$

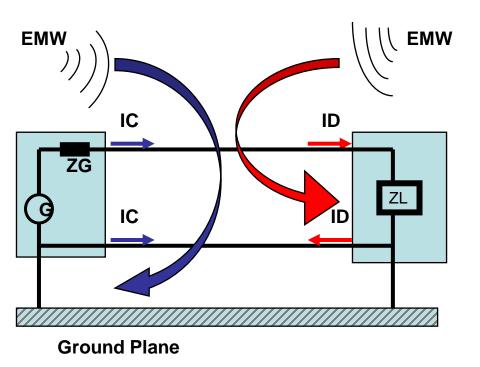


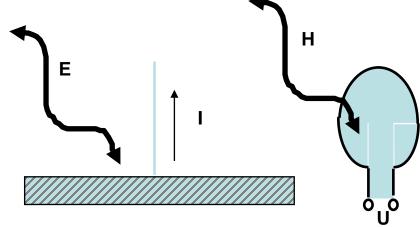
EMW to Wires and Loops

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$$\frac{E}{H} = \sqrt{\frac{\mu}{\varepsilon}} = 120\pi \cong 377\Omega$$





Wire or Loop ? ≡ Electric or Magnetic dipole?

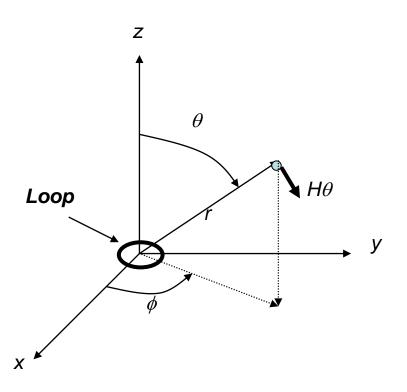
♦ Wire, Loop, surface, slot♦ cable, feed line



Reciprocity $E, H \Leftrightarrow V, I$

Radiating Loop

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Near field (freq independant):

$$H = H_0 \sqrt{\frac{3\cos(2\theta) + 5}{8}}$$

Far Field (freq dependant):

$$H = \frac{IS\beta^2}{4\pi r} \sin \theta$$

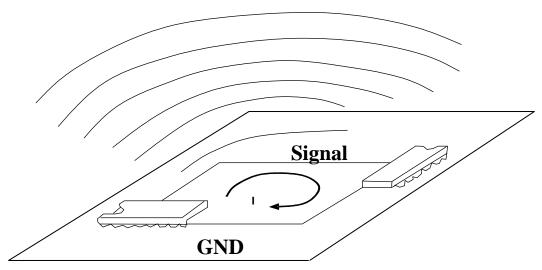


Receiving Loop



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Incident/Radiated perturbations



Radiation Loop/Captation Area

☐ Low Frequency: Length $<< \lambda$

$$e = -\frac{\partial \phi}{\partial t} = -j\omega * (\mu_0 \mu_r) * H * S * \cos(\vec{B}, \vec{S})$$

How to reduce e

F↓ !!!!!!

Relative Permeability ↓ air

Н↓

Area ↓

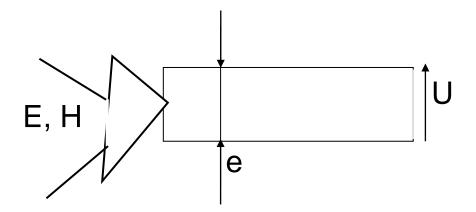
Cos(B,S) ↓

Receiving Loop



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$$\Box$$
 HF Length, L \cong λ



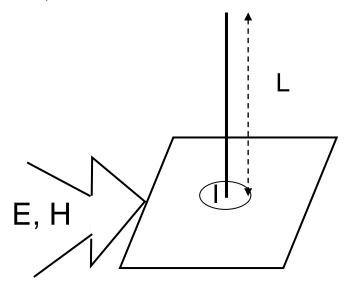
Worst case: $U_{max} = 600 \cdot e \cdot H$

U:V, e:m, H:A/m



Receiving Wire

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□ Low Frequency: L << $\lambda/4$

$$I \cong \frac{EL}{100\lambda}$$
; I:A, E:V/m, L:m, λ :m

Example: f= 945 kHz , L= 10 m, E= 300 V/m

$$\rightarrow$$
 I \simeq 94,5 mA

□ High Frequency L≅ λ (Worst case)

$$I_{\text{max}} = \frac{E\lambda}{240}$$

 $I_{max}:A, E:V/m, \lambda:m$

Example: f = 100 MHz, L= 1 m, E= 10 V/m

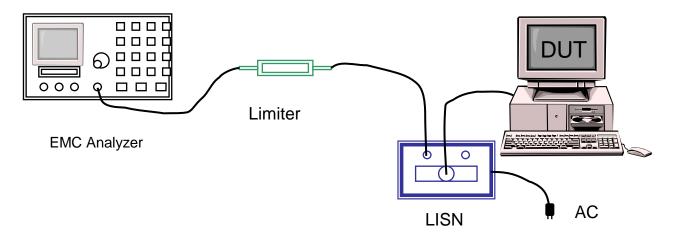
$$\rightarrow$$
 I_{max} = 125 mA

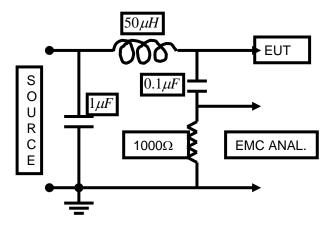


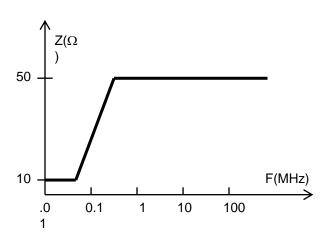


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Conduction





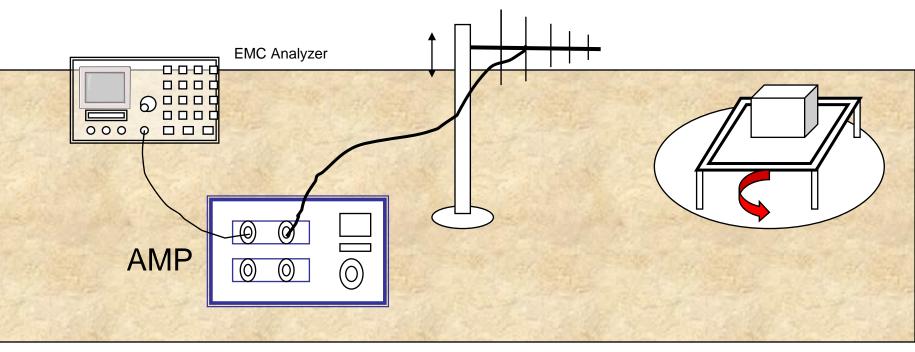






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Radiation/OATS



Ambients in OATS

Anechoic Chamber

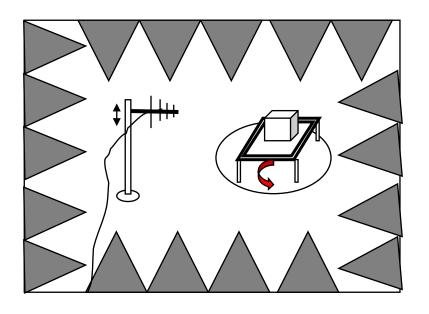
TEM / GTEM Cell

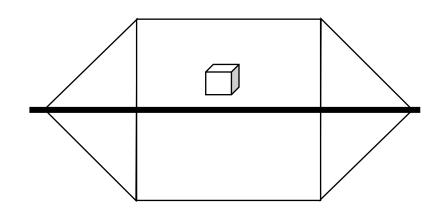




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Anechoic chamber TEM/GTEM cell





Efficency for low frequencies!!
High cost
Small Size

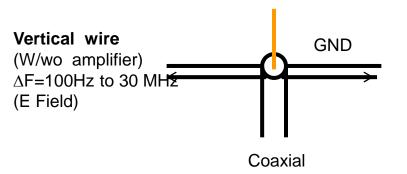




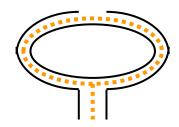
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EMC Antennas and AF

$$E(\mu V/m)=V_e(\mu V)$$
 . $K(m^{-1})$ ou $E(dB\mu V/m)=V_e(dB\mu V)+K(dB)$ (to be measured) (Read) (Given)



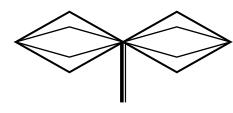
Loop ∆F=10KHz to 30 MHz (H Field)



Resonant dipoles (w/wo amplifier)

ΛF=30MHz to 1 GHz

Biconic Antenna ΔF=20 MHz to 300 MHz

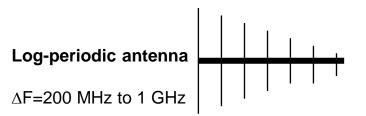




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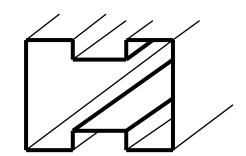
EMC Characterization



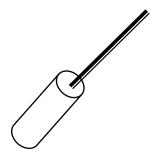
Log-spiral antenna ΔF1=200 MHz to 1 GHz ΔF2=1 GHz to 10 GHz



double-ridged horn Δ F1=200 MHz to 2 GHz Δ F2=1 GHz to 18 GHz



Search coil '

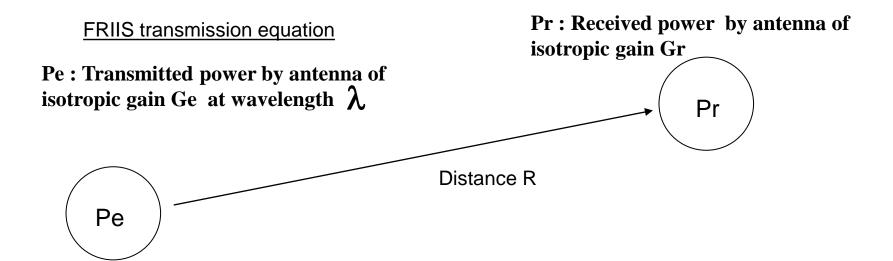






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FRIIS transmission equation



FRIIS:
$$Pr = GeGr(\lambda/(4\pi R))^2 Pe$$

Electric field created by a isotropic antenna at the distance R:

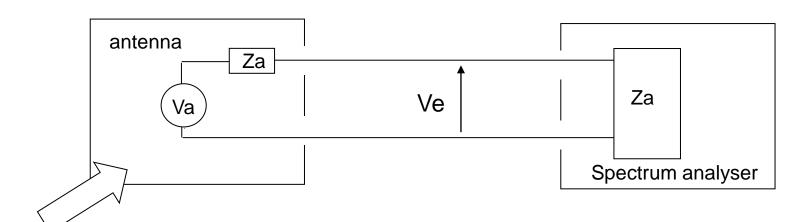
$$E \approx \frac{1}{R} \sqrt{30Pe}$$
 (With E: V/m and R: m)





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Antenna Factor



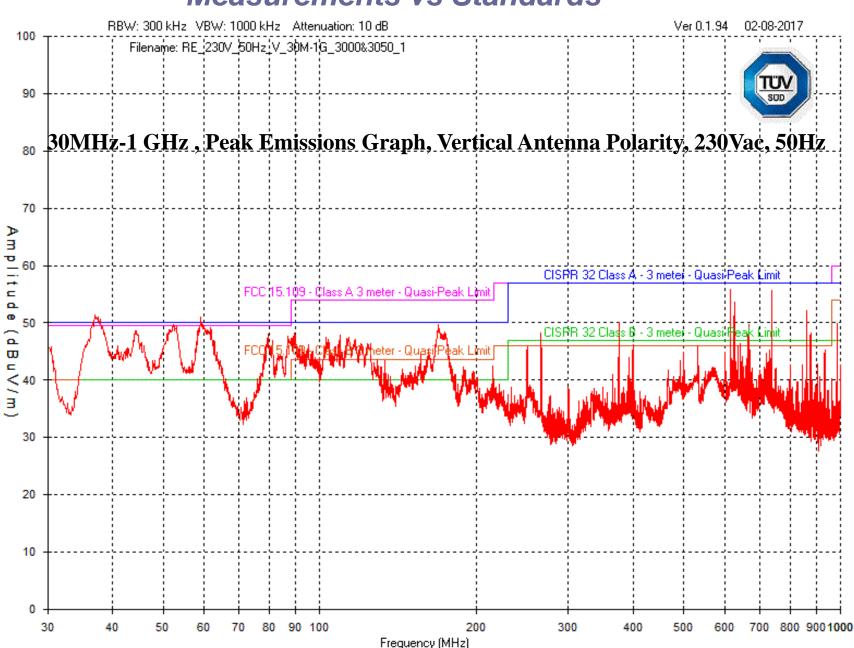
Fields E, H

E=Ve K Avec (E: V/m and K: 1/m) or (E: μ V/m and K: 1/m)

 $E = Ve + K \quad (E : dB\mu V/m \text{ and } K : dB)$

 $G = 20\log(9.73/\lambda) - AF$

Measurements vs Standards





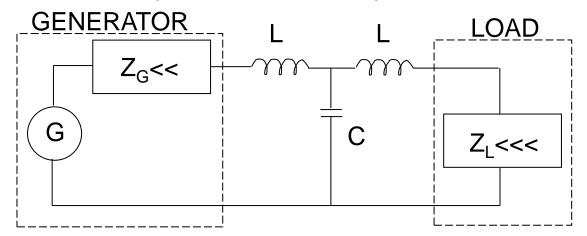


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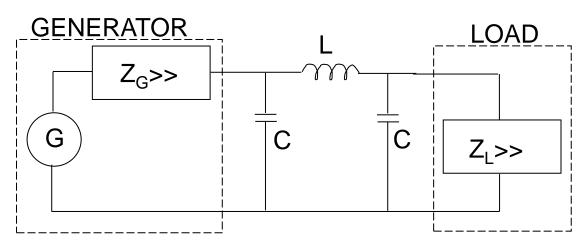
Filtering

☐ Low pass filter, band stop filter,



L with Z_G , Z_L small

C with Z_G , Z_I large



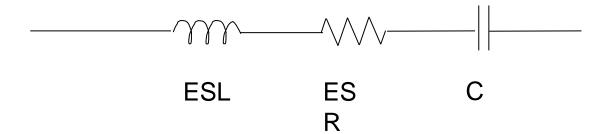


Design Guides



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Typical Capacitor Model



Electrolytic capacitors made of tantalum or aluminium:

- high capacitance
- but high ESL
- generally only used for low frequency and energy storage

mylar capacitors are small relatively inexpensive and used trough ten to a few hundredths of a MHz

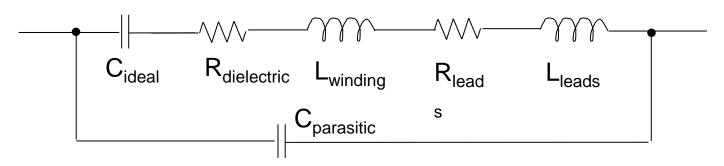


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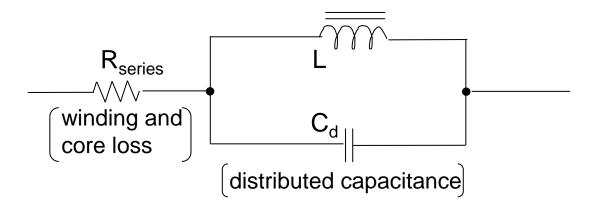
HF Capacitor Model

* High frequency capacitor model



- parallel resonant frequency

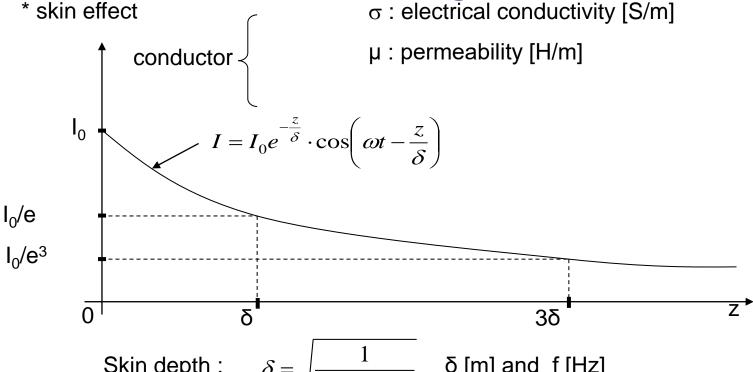
* Typical inductor model





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Shielding



$$\delta = \sqrt{\frac{1}{\pi \cdot f \cdot \mu \cdot J}}$$

 δ [m] and $\,f$ [Hz]

* N.A.

copper

$$\sigma = 5.8 * 10^{7} [S/m]$$

$$\mu = \mu_0 = 4\Pi*10^{-7} [H/m]$$

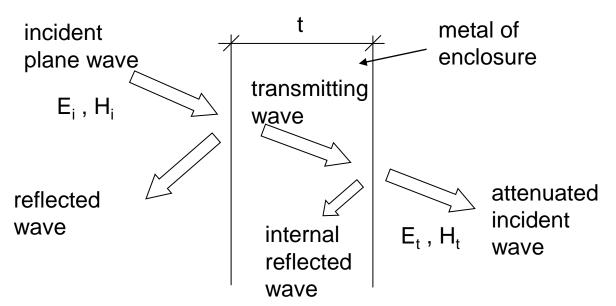
f	50 Hz	10 kHz	1 MHz	100 MHz	10 GHz
delta	9.35 mm	0.66 mm	66 µm	6,6 µm	0,66 µm



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Shielding effectiveness



Electric filed : SE_e (dB) = 20 log (E_i/E_t)

Magnetic filed : SE_h (dB) = $20log (H_i/H_t)$

Conducting factors : SE = R + A + B

R: reflection loss in dB

A: transmission or absorption loss in dB

B: internal reflection loss in dB (usually neglected)



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SE Summary

* Absorption loss:
$$A[dB] = 8.68 \cdot \frac{t}{s}$$

* Near filed zone:

$$\mathbf{R}_{h} \left[\mathbf{dB} \right] = 131.43t \sqrt{\mathbf{f} \mu_{r} \sigma_{r}} + 74.6 - 10 \log \left(\frac{\mu_{r}}{\sigma_{r} \cdot \mathbf{f} \cdot \mathbf{r}^{2}} \right)$$

$$\begin{split} R_{h} \Big[dB \Big] &= 131.43t \sqrt{f \mu_{r} \sigma_{r}} + 74.6 - 10 log \Bigg(\frac{\mu_{r}}{\sigma_{r} \cdot f \cdot r^{2}} \Bigg) \\ R_{e} \Big[dB \Big] &= 131.43t \sqrt{f \mu_{r} \sigma_{r}} + 141.7 - 10 log \Bigg(\frac{\mu_{r} \cdot f^{3} \cdot r^{2}}{\sigma_{r}} \Bigg) \end{split}$$

* for plane waves :

$$SE_e = SE_h = 131.43t\sqrt{f \ \mu_r \sigma_r} + 108.1 - 10log\left(\frac{\mu_r}{\sigma_r}f\right)$$

r = Source-to-Shield Distance in m with:

t = Shield Metal Thickness in mm

f = Frequency in MHz

, $\delta = Skin Depth in mm$

 μ_r = Relative Permeability of Copper,

 σ_r = Conductivity Relative to Copper

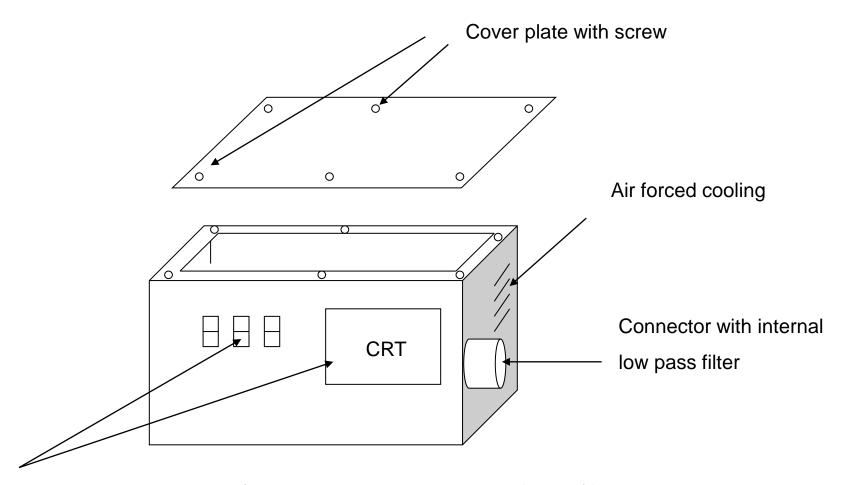
Example: f = 10 kHz, r = 10 cm, $\sigma_{cu} = 5.7 \cdot 10^7 \text{ S/m}$, $\mu = \mu_0 = 4\pi 10^{-7} \text{ H/m}$, $A \sim 10 \text{ dB}$, $SE_e \sim 118 \text{ dB}$, $SE_h \sim 44 \text{ dB}$ ($SE_e >> SE_h$) t = 0.8 mm





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Control Apertures Leakages



viewing window apertures (optically transparent and RF reflective)for alphanumeric display or CRT

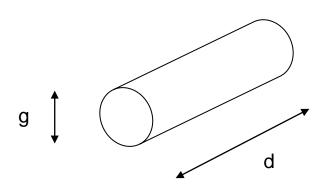


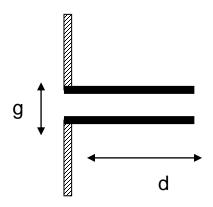


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Apertures and HoneyComb Shielding

Deep aperture with round holes





$$A (dB) = 32 (d/g)$$

Typical application: input of fiber optic (f.o.)

f.o.

Example. : g = 3 mm and d = 15 mm

A = 160 dB



Mitigation Techniques

Innov'COM

مضر التجديد في الأجهزة الجوالة، المتواصلة والمتعاونة Innovation of COMmunicant and COoperative Mobiles

Transfert Impedance

Transfert impedance Zt of coaxial line

$$1 < \frac{\lambda}{2}$$

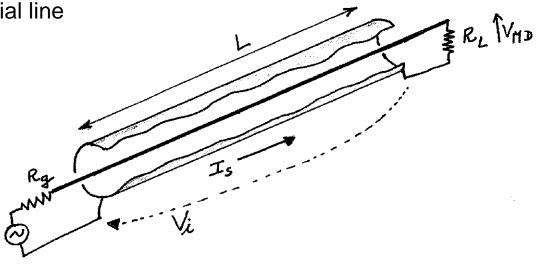
$$Zt = \frac{Vi}{Is.l} \quad \Omega$$

Zt: (V/m)

I: (m)

Vi:(V)

Is: (A)



Example. : I=5m coaxial line with Is=100 mA and f= 1 MHz

RG58/U : Zt= 14 m Ω /m

 $\qquad \qquad \Longrightarrow$

Vmd = 3.5 mV (single shield)

RG214 : $Zt = 5 \text{ m}\Omega/\text{m}$

<u></u>

Vmd = 1.25 mV (double shield)



Exercise



مخبر التجديد في الاجهزة الجوالة، المتواصلة والمتعاونة Innovation of COMmunicant and Occoperative Mobiles

Transfer Impedance

Exercise:

Which of the following cable transfer impedance measurement results corresponds to the cable with the best shielding

- a) $2 m\Omega$
- b) 10MΩ
- c) 0dB
- d) 100dB

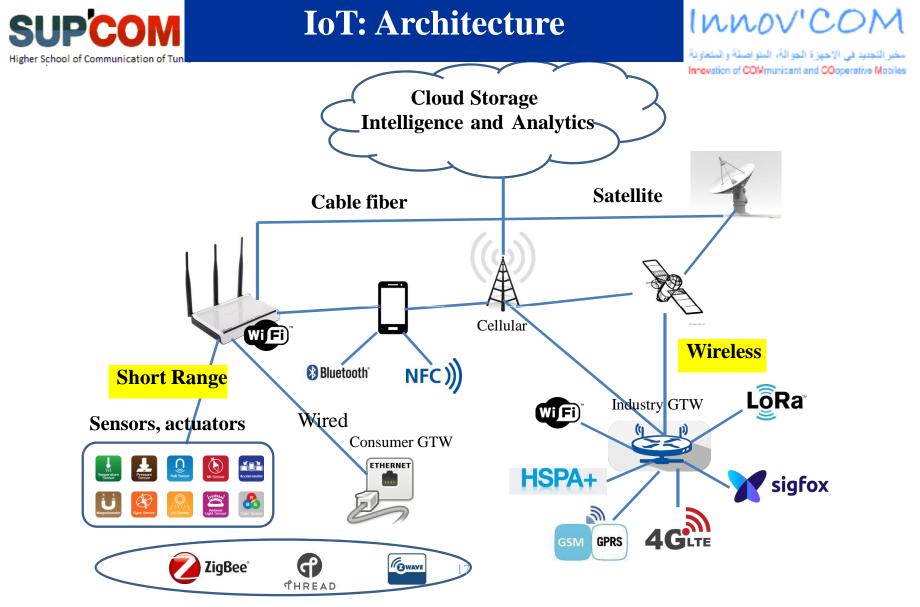
Answer:

Cable Transfer impedance measurements induce a current on the cable shield and measure the voltage induced in the signal wire terminations.

The transfer impedance is the ratio of the induced voltage to the excitation current.

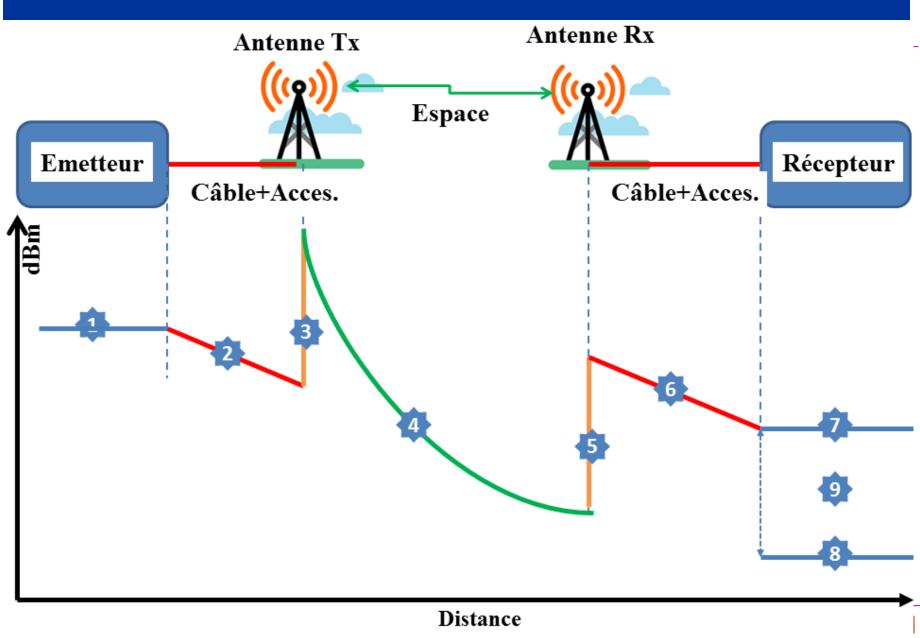
Smaller values imply better shielding.

Note that the last two options are not impedances.



IoT: Communications AND Radio

Budget Link





Rapport Signal à Bruit

مغير التجديد في الأجهزة الجوالة، المتواصلة والمتعاولة movation of COMmunicant and COoperative Mobiles

$$S/B = S/N$$
, SNR , C/I , C/N , $C/(N+I)$



$$P_r = P_t G_t G_r \left(\frac{\lambda}{4\pi d}\right)^2 \frac{1}{\alpha_{\rm R} \alpha_{\rm G} \alpha_{\rm A}} \quad (w)$$

Matching Power Control Cable Loss

Components, Filtring
Processing, Modulation,
Nonlinearities & Linearization

Pt = Transmitted Power,

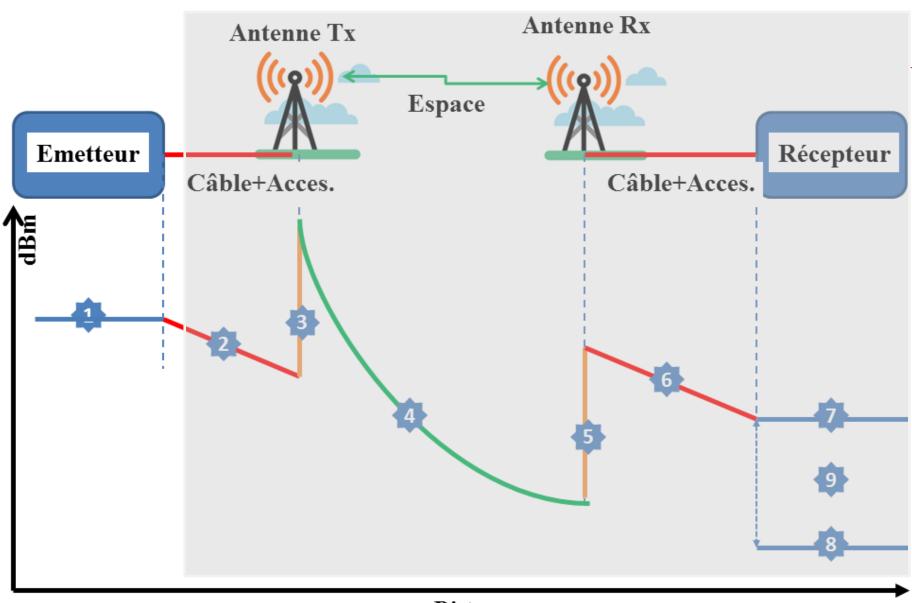
Gt = Transmitter Antenna Gain

Pr = Received Power
Gr = Receiver Antenna Gain

d = **Distance** between transmitter and receiver

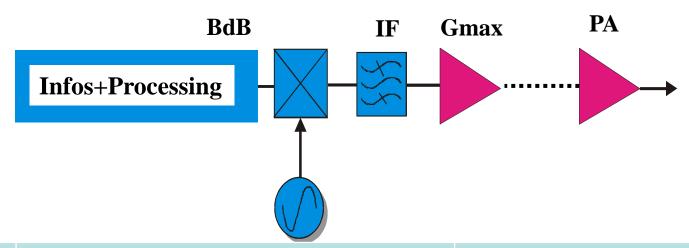
 α_B , α_G , α_A = Losses of connectors, guides and hydrometeor, respectively

+: Matching, Polarization, Antenna Pointing



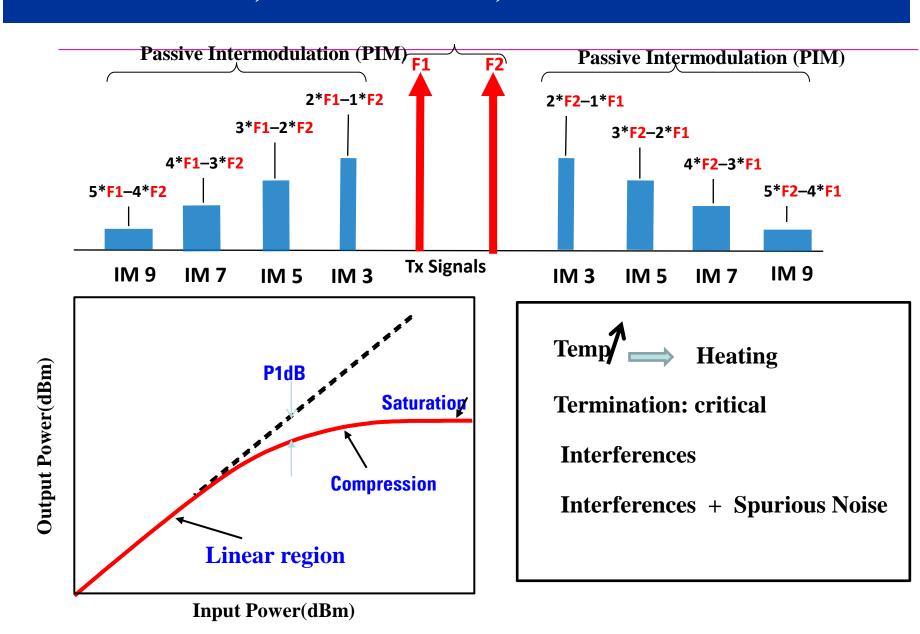
Distance

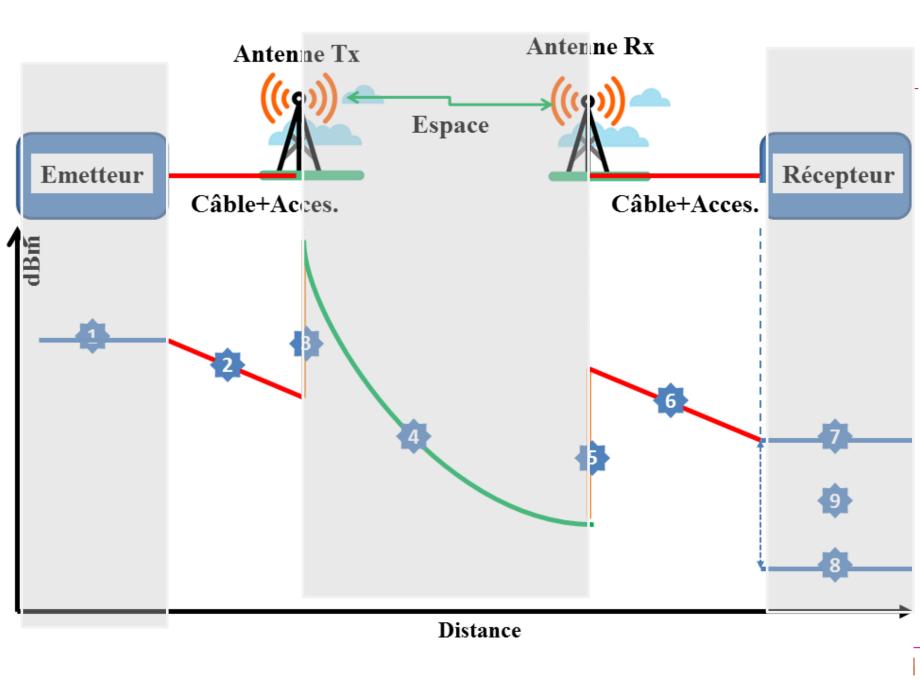
Block Diagram of a Transmitter



Technology	Range (m)	Power(mW)
BlueTooth	~ 10	~ 2,5
WiFi	~ 50	~ 80
3G/4G	~ 5000	~ 500
Lora(LPWAN)	2000-5000 (urbain), 5000-15000(rural)> 15000(LOS)	~ 20 (dépend.region)

PA, Non-linearities, IM Products





Lignes de Transmission (Structures de guidage)

Ligne bifiliare ou Multiconducteurs

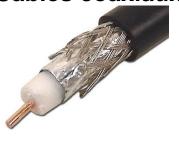








Câbles coaxiaux







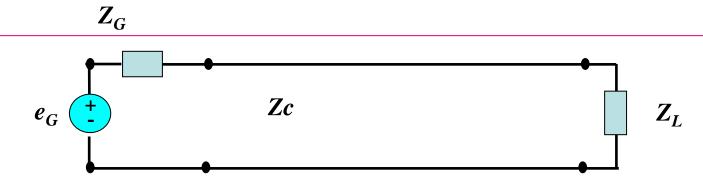
Lignes microrubans







Characteristic Z, Reflection Coefficient, SWR, Matching



$$Z_c = \frac{60}{\sqrt{\varepsilon_r}} Ln \frac{D}{d}$$

$$\Gamma_L = \frac{Z_L - Z_c}{Z_L + Z_c}$$

Coaxial:
$$Z_c = \frac{60}{\sqrt{\varepsilon_r}} Ln \frac{D}{d}$$
 $\Gamma_L = \frac{Z_L - Z_c}{Z_L + Z_c}$ $VSWR = ROS = \frac{1 + |\Gamma_L|}{1 - |\Gamma_L|}$

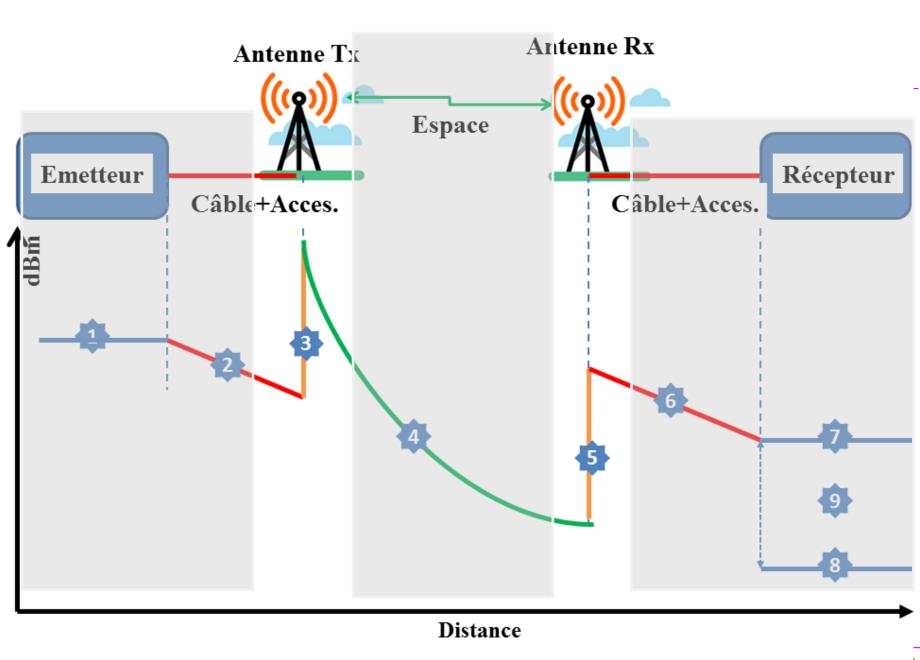
Matching:
$$Z_L = Z_c \leftrightarrow \Gamma_L = 0 \leftrightarrow VSWR = 1$$
 $P_t = P_{inc}(1 - |\Gamma|^2)$

$$P_t = P_{inc}(1 - |\Gamma|^2)$$

1/2inch Cable Loss:

Туре		1800MHz	2100MHz
½ inch	7	10	11

- Exemple: Loss of a 67m portion at 1800MHz
- Answer= $67x0,1=6,7dB + Coonector Losses \rightarrow Lees than 25\% of power transmitted$



Different kinds of Antennas



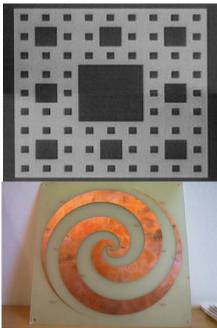


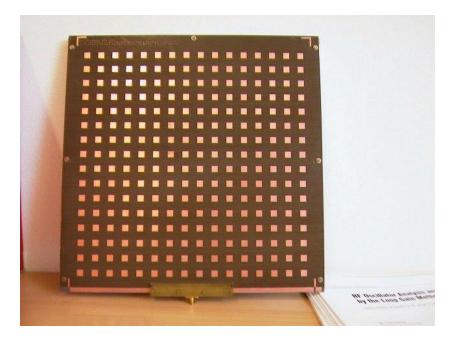




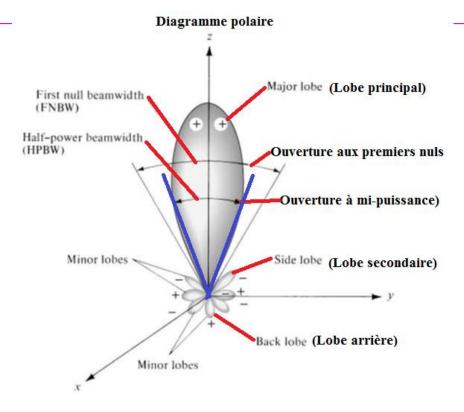




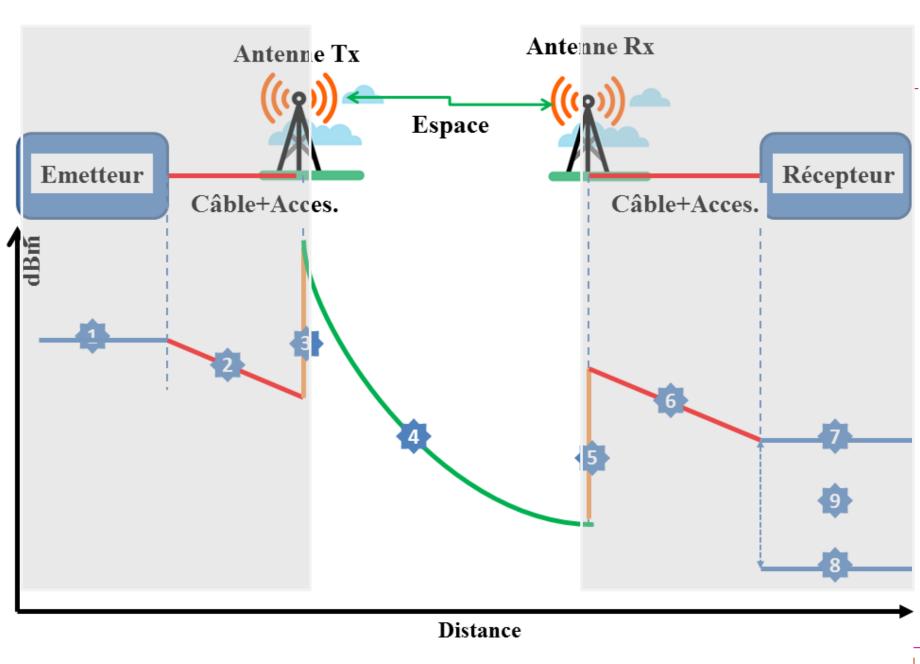




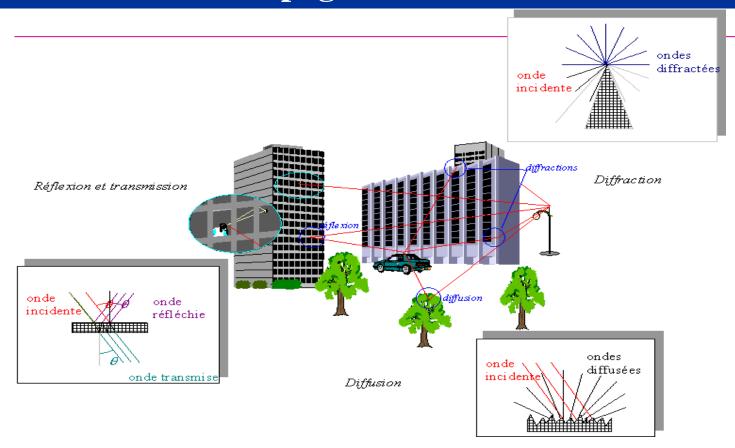
Antennas Characteristics



- Reciprocity
- Radiation Pattern
- Gain & Directivity vs Effective area
- Radiation Resistance, Impedance and Resonance
- Image principle and Effect of Ground Planes
- Polarization
- Arrays, Nonintentional



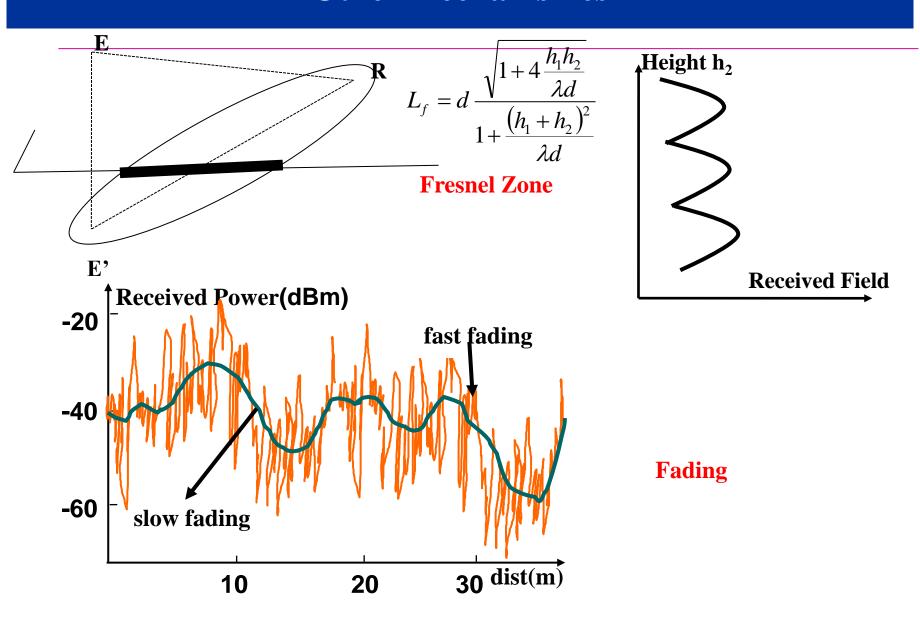
Propagation Mechanisms

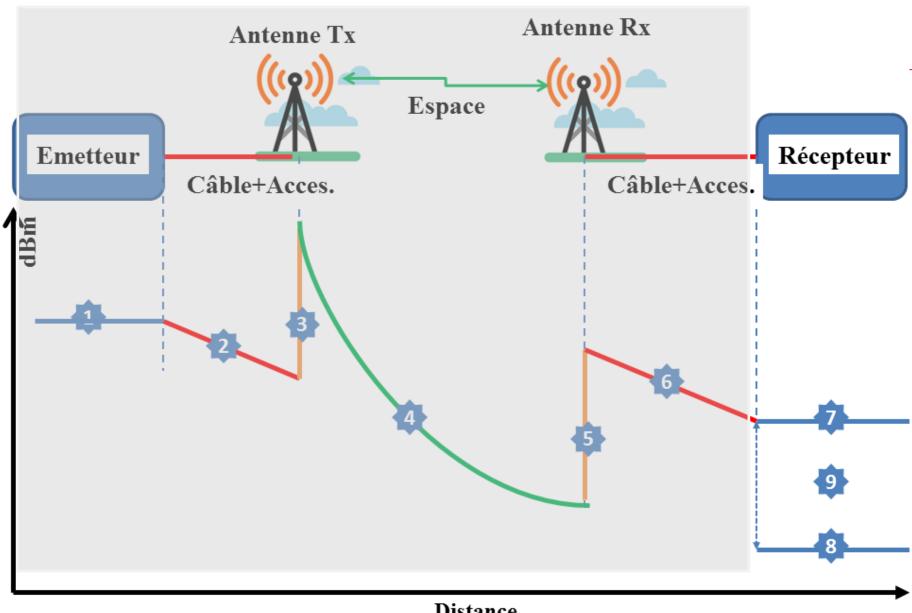


- ☐ Indoor, Outdoor, Free space, LOS, Satellites, Models
- ☐ Reflection, Refraction, Diffraction, Scattering, Absorption, Doppler,...

- ☐ Amplitude, Phase Distortion
- ☐ Slow and Fast Fading
- ☐ Propagation Models

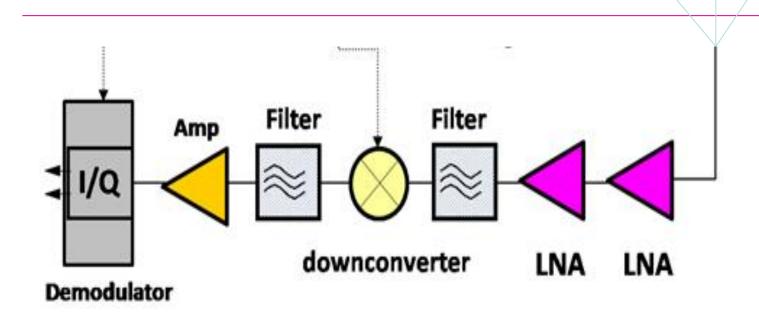
Other mechanismes





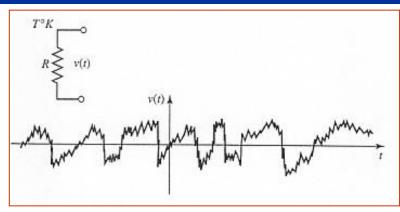
Distance

Receiver Block Diagram

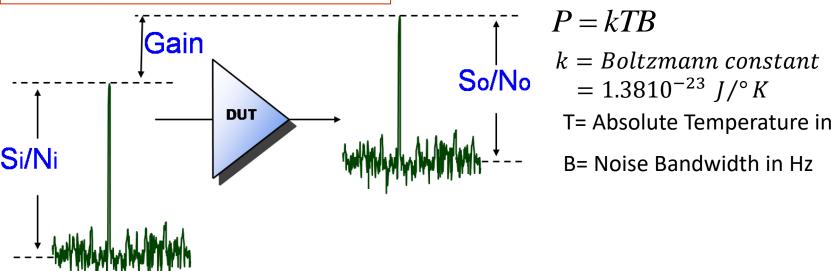


Receiver Sensibility
Margin
Low Noise Amplifier (LNA)

Noise and Noise Factor/Figure



Thermal Noise, Shot Noise, Flicker,.... **⇔** Thermal Noise generated by a resistor heated to an absolute temperature T°K:



$$P = kTB$$

T= Absolute Temperature in K

B= Noise Bandwidth in Hz

B= Noise Bandwidth in Hz

$$F_T = F_1 + \frac{F_2 - 1}{G_1} + \frac{F_3 - 1}{G_1 G_2} + \dots + \frac{F_n - 1}{G_1 G_2 \dots G_{n-1}}$$

$$=\frac{\left(\frac{1}{N_{i}}\right)}{\left(\frac{S_{o}}{N_{o}}\right)}$$

$$NF = 10 \log \left| \frac{\left(\frac{S_i}{N_i}\right)}{\left(\frac{S_o}{N_o}\right)} \right|$$

Conclusion: When consider RF techniques?

- Component models (Bahavior of R, L, C, Diodes, Transistors)
- * Single and coupled Transmisison Lines (xTalk, matching, coupling)
- * Amplifiers (Gmax, LNA, PA), Oscillators, Mixers (NLinearities and IM products)
- * Antennas and Propagation (Design and Radio Planning)
- * Transmitters and Receivers (Range, sensibility and efficiency)
- * EMC and interferences
- * Electromagnetic Fields effects and Health risks

Thank you



Merci